


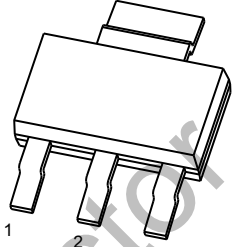
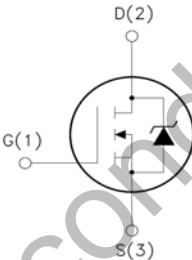
SYM601

Features:

- Low Intrinsic Capacitances.
- Excellent Switching Characteristics.
- Extended Safe Operating Area.
- Unrivalled Gate Charge :Qg=7.7nC (Typ.).
- BVDSS=600V, I_D=1A
- R_{DS(on)} : 8Ω (Max) @V_G=10V
- 100% Avalanche Tested



SOT-223

1.Gate (G)
2.Drain (D)
3.Source (S)
Marking:SYM601

Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	600	V
V _{GS}	Gate-Source Voltage	±30	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V	1.0	A
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V	0.7	A
I _{DM}	Pulsed Drain Current ¹	6	A
P _D @T _C =25°C	Total Power Dissipation	26	W
	Linear Derating Factor	0.21	W/°C
E _{AS}	Single Pulse Avalanche Energy ²	13	mJ
I _{AR}	Avalanche Current	1.0	A
E _{AR}	Repetitive Avalanche Energy	0.5	mJ
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Value	Units
R _{thj-c}	Thermal Resistance Junction-case	Max. 4.7	°C/W
R _{thj-a}	Thermal Resistance Junction-ambient	Max. 110	°C/W

Electrical Characteristics @ $T_j=25^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=1mA$	600	-	-	V
$\Delta BV_{DSS}/\Delta T_j$	Breakdown Voltage Temperature Coefficient	Reference to $25^{\circ}\text{C}, I_D=1mA$	-	0.6	-	V/ $^{\circ}\text{C}$
$R_{DS(ON)}$	Static Drain-Source On-Resistance	$V_{GS}=10V, I_D=0.5A$	-	7.2	8	Ω
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
g_{fs}	Forward Transconductance	$V_{DS}=50V, I_D=0.5A$	-	0.8	-	S
I_{DSS}	Drain-Source Leakage Current ($T_j=25^{\circ}\text{C}$)	$V_{DS}=600V, V_{GS}=0V$	-	-	10	μA
	Drain-Source Leakage Current ($T_j=150^{\circ}\text{C}$)	$V_{DS}=480V, V_{GS}=0V$	-	-	100	μA
I_{GSS}	Gate-Source Leakage	$V_{GS}=\pm 30V$	-	-	± 100	nA
Q_g	Total Gate Charge ³	$I_D=1.0A$	-	7.7	-	nC
Q_{gs}	Gate-Source Charge	$V_{DS}=480V$	-	1.5	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	$V_{GS}=10V$	-	2.6	-	nC
$t_{d(on)}$	Turn-on Delay Time ³	$V_{DD}=300V$	-	8	-	ns
t_r	Rise Time	$I_D=1.0A$	-	5	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=10\Omega, V_{GS}=10V$	-	14	-	ns
t_f	Fall Time	$R_D=187.5\Omega$	-	7	-	ns
C_{iss}	Input Capacitance	$V_{GS}=0V$	-	286	-	pF
C_{oss}	Output Capacitance	$V_{DS}=25V$	-	25	-	pF
C_{rss}	Reverse Transfer Capacitance	$f=1.0MHz$	-	5	-	pF

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
I_S	Continuous Source Current (Body Diode)	$V_D=V_G=0V, V_S=1.5V$	-	-	1.0	A
I_{SM}	Pulsed Source Current (Body Diode) ¹		-	-	6	A
V_{SD}	Forward On Voltage ³	$T_j=25^{\circ}\text{C}, I_S=1.0A, V_{GS}=0V$	-	-	1.5	V

Notes:

1. Pulse width limited by safe operating area.
2. Starting $T_j=25^{\circ}\text{C}$, $V_{DD}=50V$, $L=10mH$, $R_G=25\Omega$, $I_{AS}=1.6A$.
3. Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

Typical Characteristics

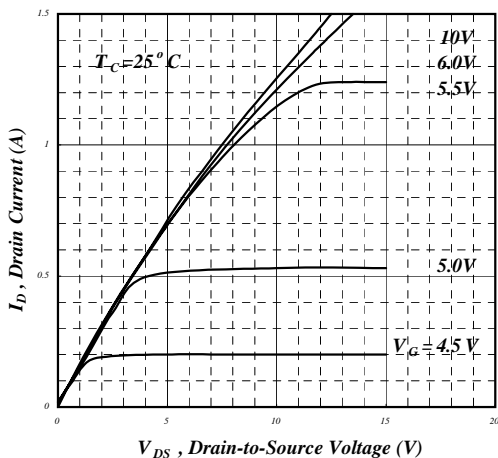


Fig 1. Typical Output Characteristics

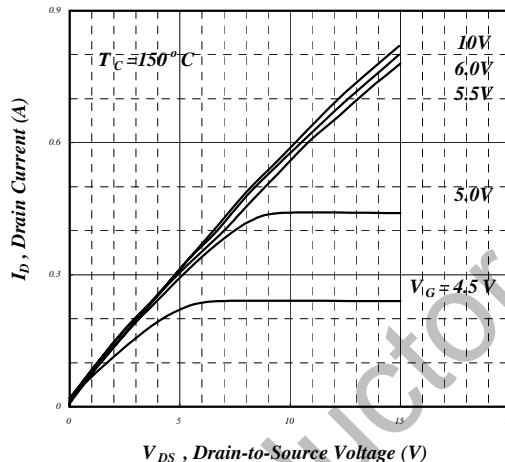


Fig 2. Typical Output Characteristics

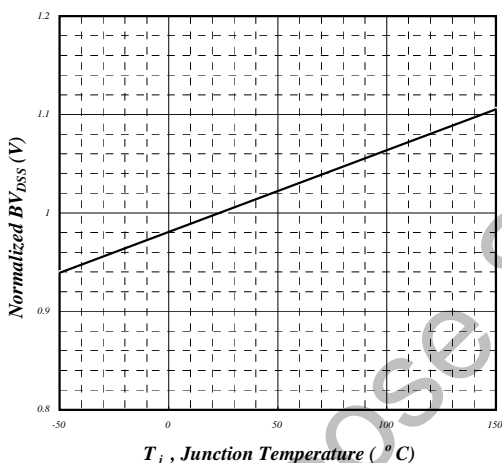


Fig 3. Normalized BV_{DSS} v.s. Junction Temperature

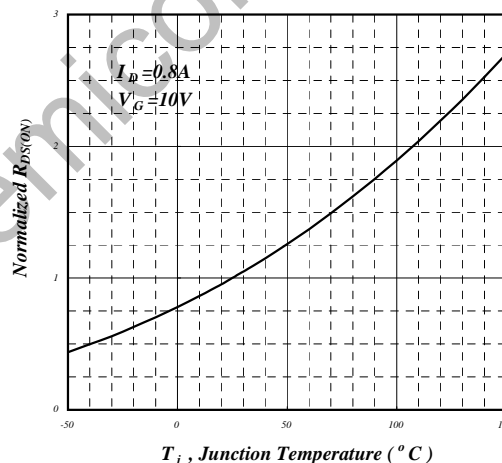


Fig 4. Normalized On-Resistance v.s. Junction Temperature

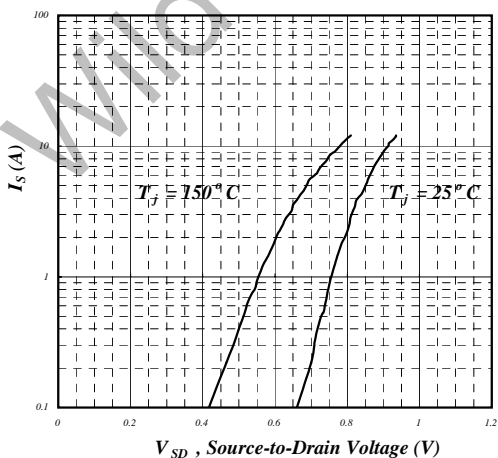


Fig 5. Forward Characteristic of Reverse Diode

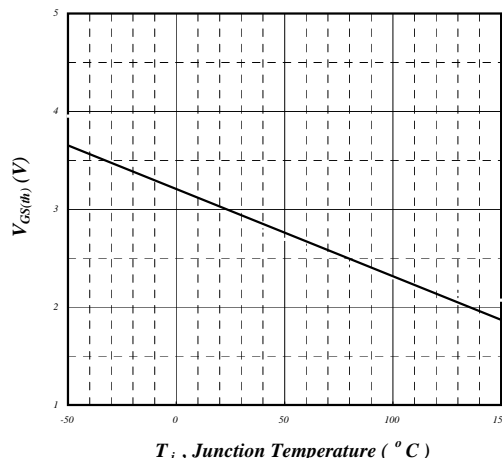


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

Typical Characteristics (Continued)

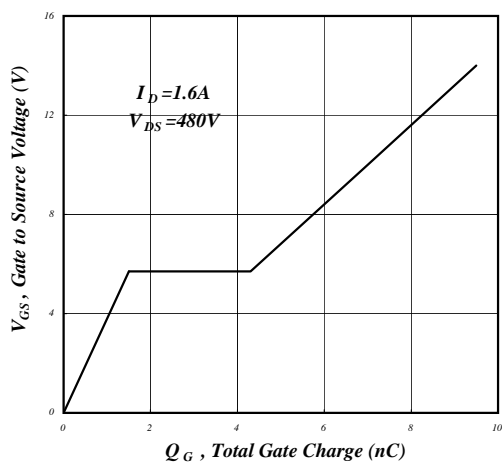


Fig 7. Gate Charge Characteristics

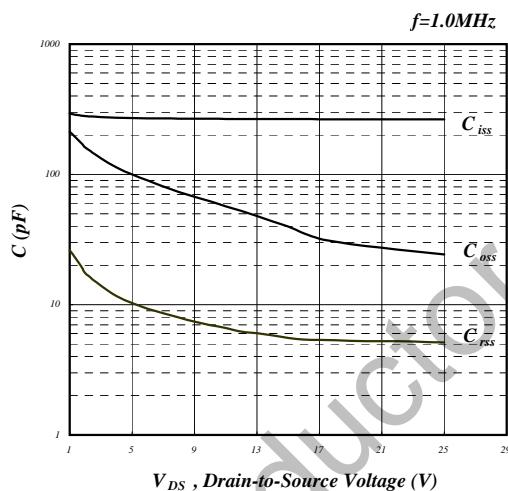


Fig 8. Typical Capacitance Characteristics

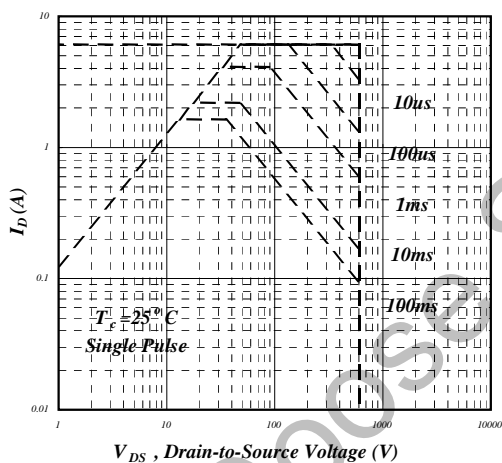


Fig 9. Maximum Safe Operating Area

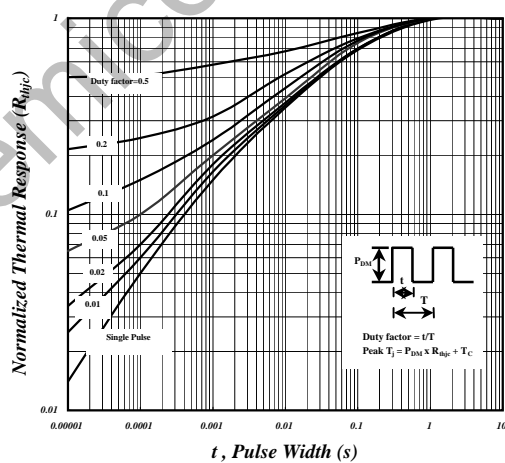


Fig 10. Effective Transient Thermal Impedance

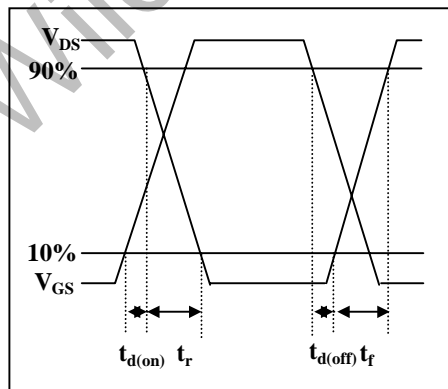


Fig 11. Switching Time Waveform

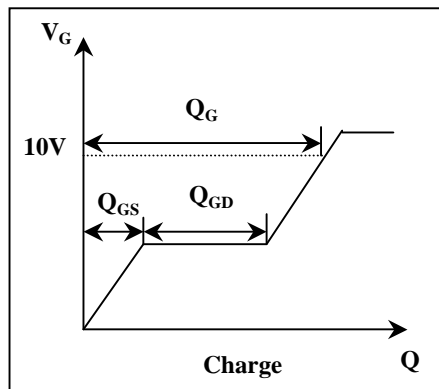
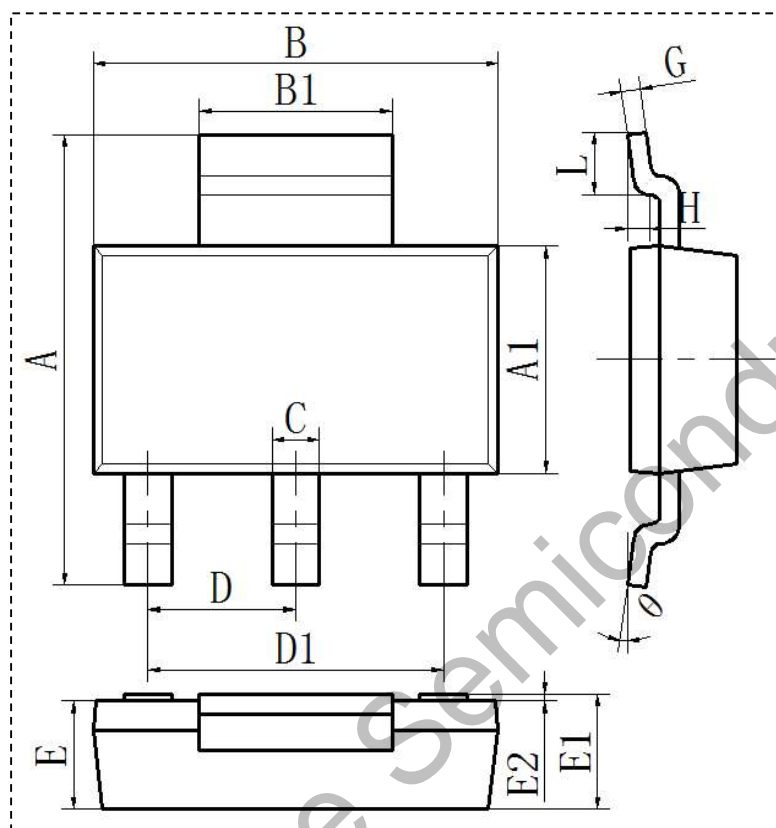


Fig 12. Gate Charge Waveform

Package Dimension**SOT-223** (单位: mm)

符号	标准	下公差	上公差	下限值	上限值
A	6.95	-0.24	0.24	6.71	7.19
A1	3.5	-0.1	0.1	3.4	3.6
B	6.4	-0.1	0.1	6.2	6.4
B1	3.00	-0.1	0.1	2.9	3.1
C	0.74	-0.08	0.08	0.66	0.82
D	2.3	-0.05	0.05	2.25	2.35
D1	4.6	-0.1	0.1	4.5	4.7
E	1.6	-0.1	0.1	1.5	1.7
E1	1.66	-0.14	0.14	1.52	1.8
E2(测试后)	/	/	/	0	0.1
E2(成型后)	/	/	/	0.02	0.08
G	0.3	-0.05	0.05	0.25	0.35
H	0.25	-0.05	0.05	0.20	0.30
L	0.95	-0.15	0.15	0.8	1.1
0	8	/	/	8	8